



DMN1150UFL3

Product Summary

Device	BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
N-Channel	12V	150mΩ @ V_{GS} = 4.5V	2.0A
N-Channer	120	185mΩ @ V_{GS} = 2.5V	1.8A

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$, yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor Control
- Power Management Functions
- Backlighting

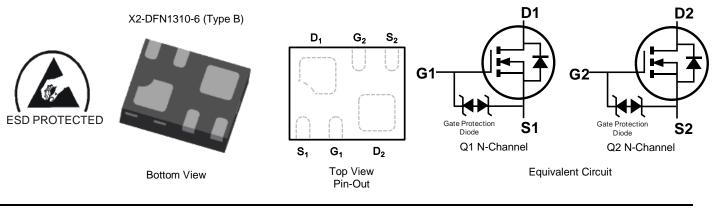
DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Footprint of just 1.3 mm²
 - Ultra-Low Profile Package 0.35mm Profile
- Low Gate Threshold Voltage
- Fast Switching Speed
- Ultra-Small Surface Mount Package
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: X2-DFN1310-6 (Type B)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @
- Weight: 0.002 grams (Approximate)



Ordering Information (Note 4)

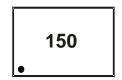
Part Number	Reel Size (inches)	Tape Width (mm)	Quantity per Reel	
DMN1150UFL3-7 7		8	3,000	
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.				

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen - and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



150 = Product Type Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	12	V		
Gate-Source Voltage	V _{GSS}	±6	V		
Continuous Drain Current (Note 5) V _{GS} = 4.5V	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	2.0 1.6	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T _A = +25°C	PD	0.39	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	320	°C/W
Total Power Dissipation (Note 6) T,		PD	0.9	W
Thermal Resistance, Junction to Ambient (Note 6) Steady S		R _{0JA}	141	°C/W
Thermal Resistance, Junction to Case (Note 6)		R _{0JC}	49	°C/vv
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

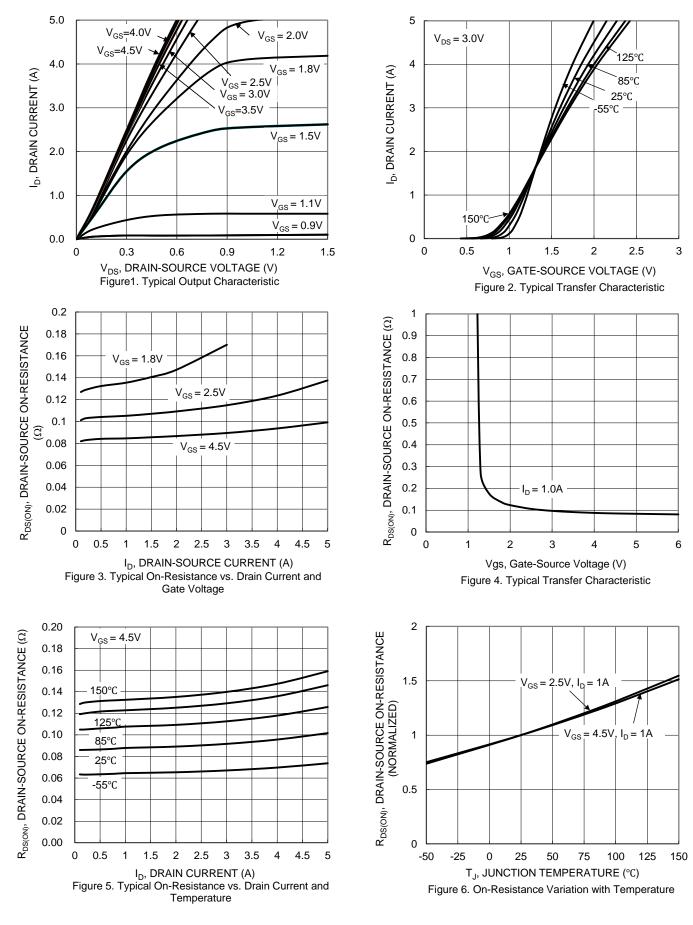
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)				•		
Drain-Source Breakdown Voltage	BV _{DSS}	12	_	—	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	_	_	1	μA	$V_{DS} = 12V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	—	_	±10	μA	$V_{GS} = \pm 6V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	0.35	0.42	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
			119	150		Vgs = 4.5V, Id = 1A
Static Drain-Source On-Resistance	R _{DS(ON)}	—	141	185	mΩ	Vgs = 2.5V, Id = 1A
	~ /		175	210		Vgs = 1.8V, Id = 1A
Diode Forward Voltage	V _{SD}	—	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 150mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	CISS	_	115	—	pF	
Output Capacitance	Coss	_	25	—	pF	− V _{DS} = 6V, V _{GS} = 0V, − f = 1.0MHz
Reverse Transfer Capacitance	C _{RSS}	_	23	—	pF	
Gate Resistance	R _G	_	90	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Q _G	—	1.4	—	nC	
Gate-Source Charge	Q _{GS}	_	0.1	—	nC	$V_{DS} = 4V, V_{GS} = 4.5V, I_{D} = 1A$
Gate-Drain Charge	Q _{GD}	—	0.1	—	nC	
Turn-On Delay Time	t _{D(ON)}	—	4.0	—	ns	
Turn-On Rise Time	t _R	_	7.4	—	ns	$V_{GS} = 6V, V_{DS} = 4V,$
Turn-Off Delay Time	t _{D(OFF)}	_	44	—	ns	$R_G = 1\Omega$, $I_D = 1A$
Turn-Off Fall Time	t _F	—	19	—	ns	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect. Notes:

8. Guaranteed by design. Not subject to product testing.



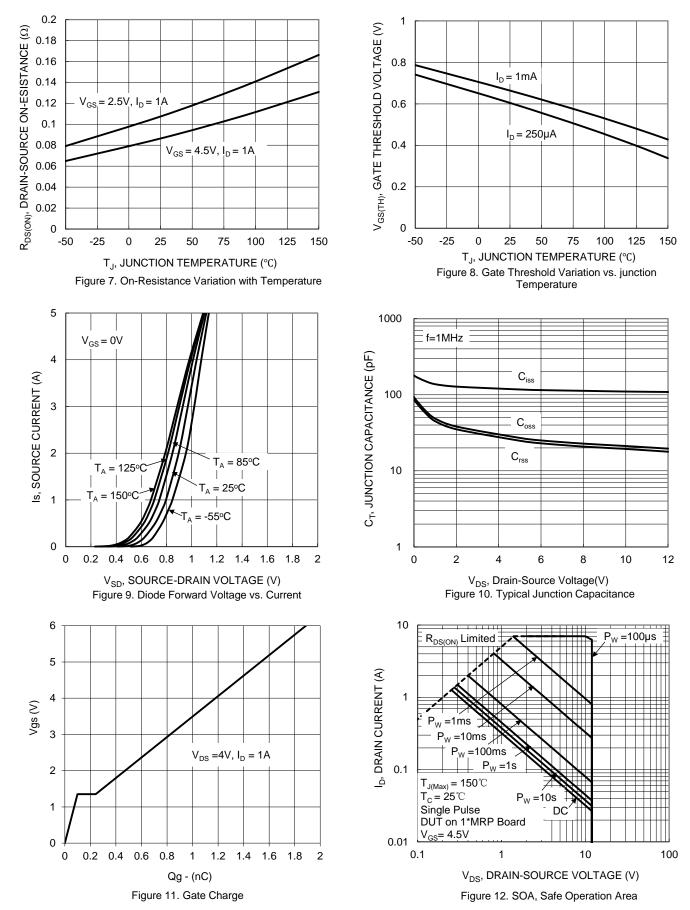
DMN1150UFL3



DMN1150UFL3 Datasheet Number: DS38572 Rev. 3 - 2 Downloaded from Arrow.com.

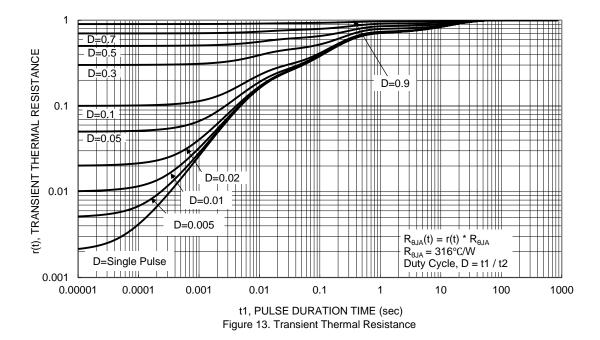


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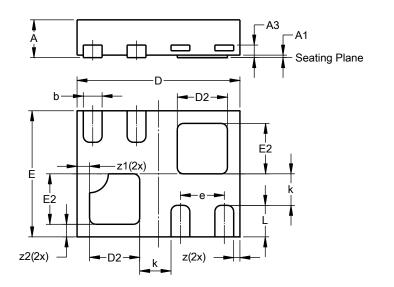




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1310-6 (Type B)

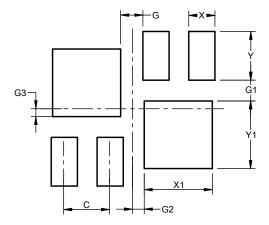


X2-DFN1310-6					
(Type B)					
Dim	Min				
Α	0.25	0.35	Typ 0.30		
A1	0	0.05	0.02		
A3			0.100		
b	0.10	0.20	0.15		
D	1.25	1.35	1.30		
D2	0.30	0.50	0.40		
ш	0.95	1.05	1.00		
E2	0.30	0.50	0.40		
е			0.35		
k	0.15				
L	0.20	0.30	0.25		
z			0.05		
z1			0.10		
z2			0.10		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X2-DFN1310-6 (Type B)



Dimensions	Value (in mm)				
С	0.350				
G	0.17				
G1	0.16				
G2	0.09				
G3	0.06				
Х	0.20				
X1	0.52				
Y	0.375				
Y1	0.52				



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